

Maximum Ratings

Symbol	Conditions	Values	Units
$V_{CEV_{SUS}}$	$I_C = 1\text{ A}$, $V_{BE} = -2\text{ V}$	600	V
V_{CEV}	$V_{BE} = -2\text{ V}$	600	V
V_{CBO}	$I_E = 0$	600	V
V_{EBO}	$I_C = 0$	7	V
I_C	D. C.	100	A
I_{CM}	$t_p = 1\text{ ms}$	200	A
$I_F = -I_C$		100	A
I_B		6	A
P_{tot}	$T_{case} = 25\text{ °C}$; per darlington	620	W
T_{vj}		-40 ... +150	°C
T_{stg}		-40 ... +125	°C
V_{isol}	a. c. 50 Hz, r.m.s.	2500~	V

Thermal Characteristics

R_{thjc}	per darlington/per module	0,2/0,1	°C/W
R_{thjc}	per diode/per module	0,6/0,3	°C/W
R_{thch}	per 1/2 module/per module	0,075/0,038	°C/W

Electrical Characteristics¹⁾

		min.	typ.	max.	
I_{CEV}	$V_{CE} = V_{CEV}$, $V_{BE} = -2\text{ V}$			2	mA
I_{EBO}	$I_C = 0$, $V_{BE} = -7\text{ V}$			300	mA
$V_{CEsat}^{2)}$	$I_C = 100\text{ A}$, $I_B = 1,3\text{ A}$			2	V
$V_{BEsat}^{2)}$	$I_C = 100\text{ A}$, $I_B = 1,3\text{ A}$			2,5	V
$h_{21E}^{2)}$	$I_C = 100\text{ A}$	$V_{CE} = 2\text{ V}$	75		
		$V_{CE} = 5\text{ V}$	100		

Switching Characteristics for Resistive Load¹⁾

t_{on}	$I_C = 100\text{ A}$ $I_{B1} = -I_{B2} = 2\text{ A}$ $V_{CC} = 300\text{ V}$		2	μs
t_s			12	μs
t_f			3	μs

Inverse Diode Characteristics¹⁾

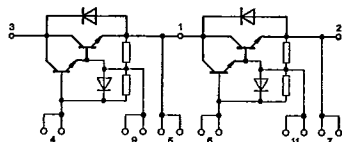
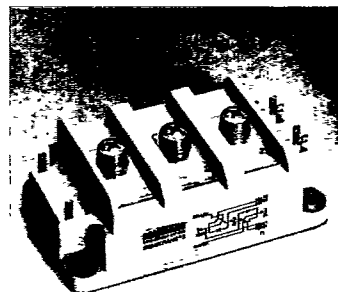
$V_F = -V_{CE}$	$I_F = -I_C = 100\text{ A}$		1,75	V
$I_{FSM} = -I_{CP}$	sin 180°, 10 ms	1000		A
I_{RM}	$I_F = -I_C = 100\text{ A}$, $-di_F/dt = 100\text{ A/μs}$ $V_{BE} = -3\text{ V}$, $V_R = V_{CE} = 400\text{ V}$ $T_{vj} = 125\text{ °C}$		38	A
Q_{rr}			19	μC

Mechanical Data

M_1	Case to heatsink	SI units	3	6	Nm
		US units	27	53	lb. in.
M_2	Busbars to terminals	SI units	2,5	5	Nm
		US units	22	44	lb. in.
w			420		g
Case			D 13		

SEMITRANS® 3 NPN
Power Darlington Modules
100 A, 600 V

SK 100 DB 060 D



Features

- Isolated baseplate (ease of mounting of one or several modules on one heatsink)
- All electrical connections on top (ease of interconnecting of modules with busbars)
- Large clearances and creepage distances
- Parallel connected fast recovery inverse diode
- UL recognized, file no. 63 532

Typical Applications

- Uninterruptible power supplies (UPS)
- DC drives
- AC motor controls

1) $T_{case} = 25\text{ °C}$ unless otherwise stated2) $t_p \leq 300\text{ μs}$, $D \leq 1,5\%$

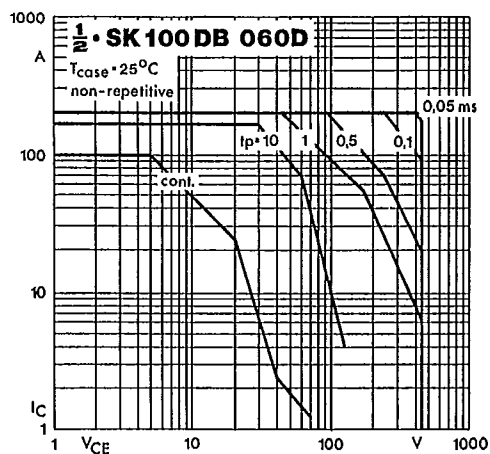


Fig. 1 Forward biased safe operating area (FBSOA)

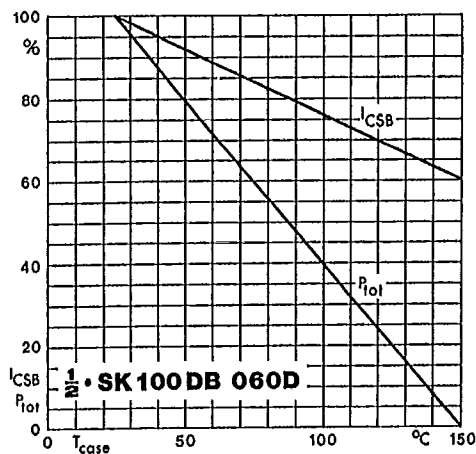


Fig. 2 Shifting the limits of the FBSOA with temperature

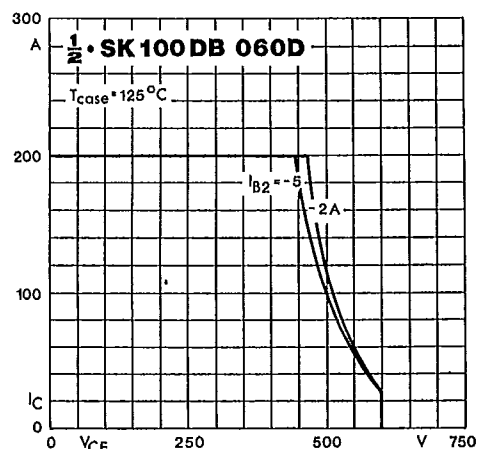


Fig. 3 Reverse biased safe operating area (RBSOA)

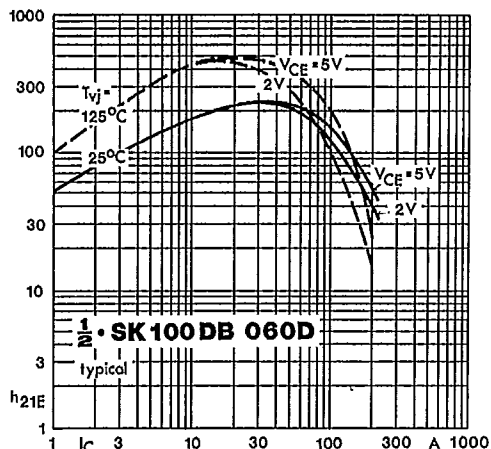


Fig. 4 Forward current transfer ratio vs. coll. current

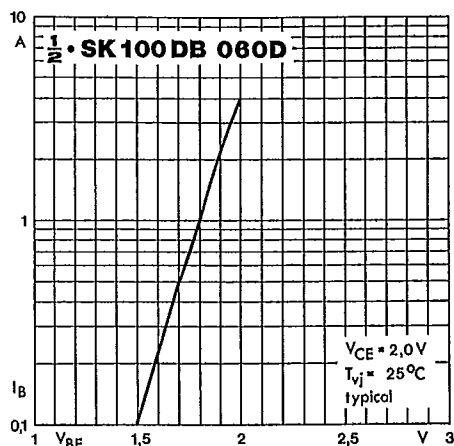


Fig. 5 Base current/voltage characteristic

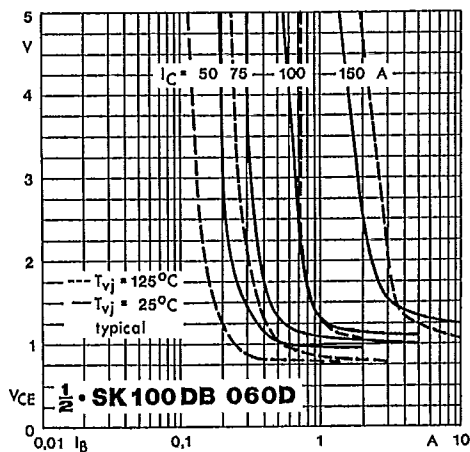


Fig. 6 Collector-emitter voltage vs. base current

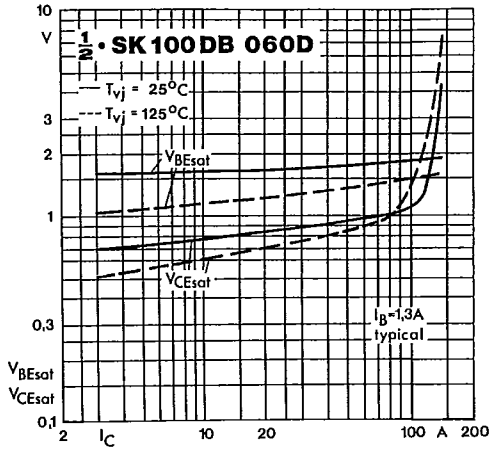


Fig. 7 Saturation voltages vs. collector current

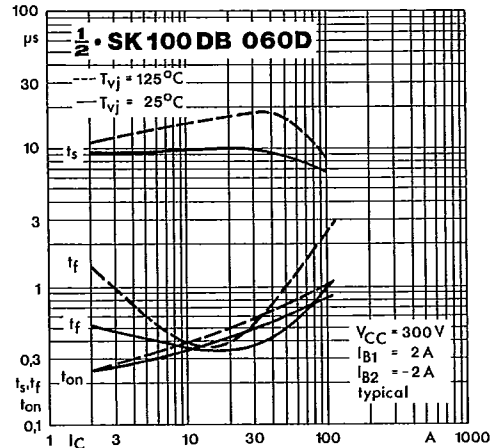


Fig. 8 Switching times vs. collector current

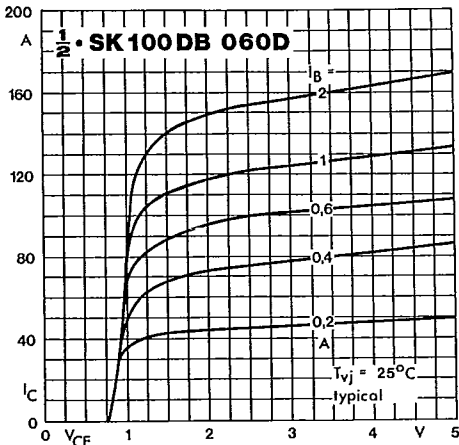


Fig. 9 Collector current/voltage characteristics

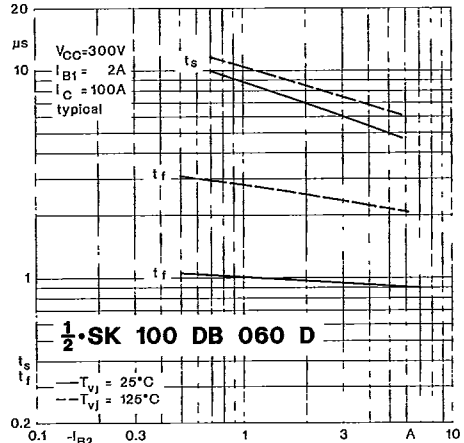


Fig. 10 Turn-off times vs. negative base current

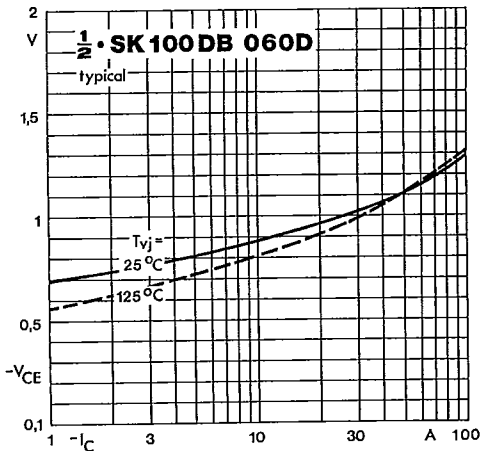


Fig. 11 Inverse diode forward characteristics

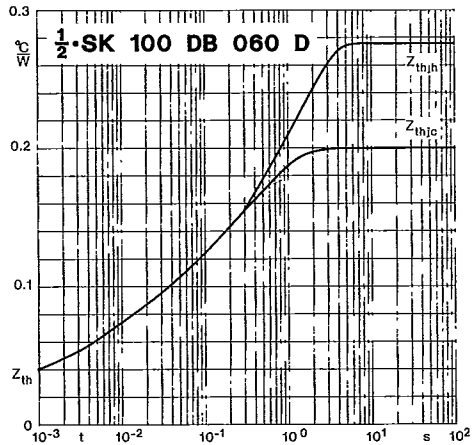


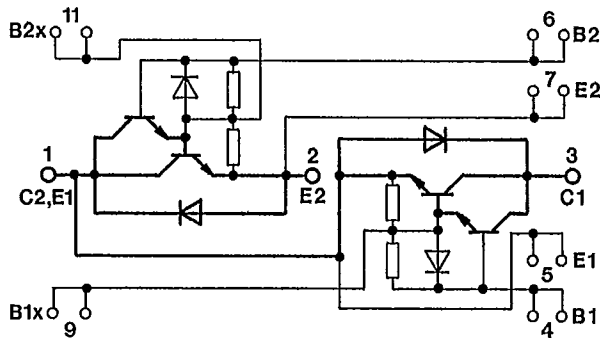
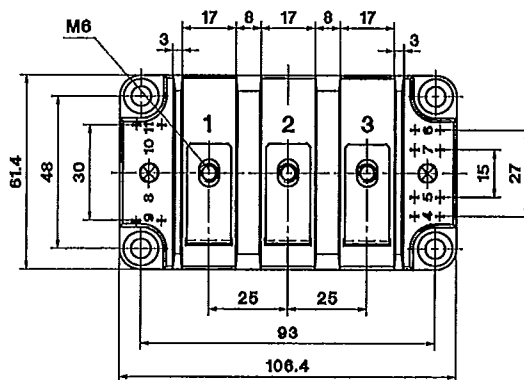
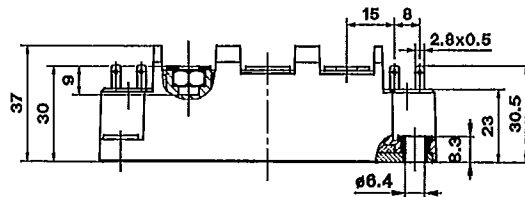
Fig. 12 Transient thermal impedance vs. time

SK 100 DB 060 D

Case D 13

SEMITRANS® 3

UL recognized, file no. 63 532



Dimensions in mm